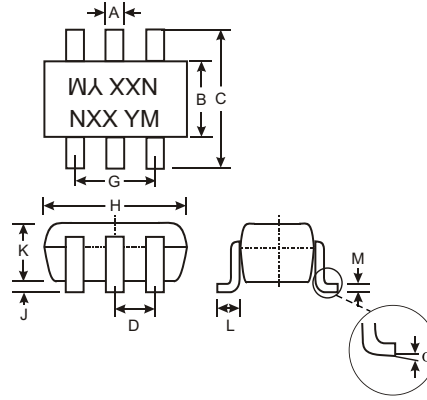


### Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors

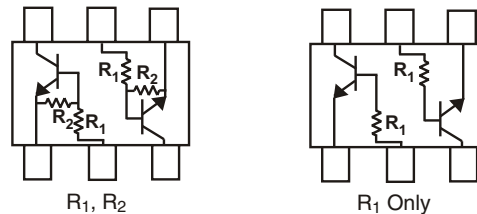
### Mechanical Data

- Case: SOT-26, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 3)
- Weight: 0.015 grams (approx.)
- Ordering Information (See Page 3)



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	0.95		
G	1.90		
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
$\alpha$	0°	8°	—
All Dimensions in mm			

P/N	R1	R2	MARKING
DDC124EK	22K $\Omega$	22K $\Omega$	N17
DDC144EK	47K $\Omega$	47K $\Omega$	N20
DDC114YK	10K $\Omega$	47K $\Omega$	N14
DDC123JK	2.2K $\Omega$	47K $\Omega$	N06
DDC114EK	10K $\Omega$	10K $\Omega$	N13
DDC143TK	4.7K $\Omega$	-	N07
DDC114TK	10K $\Omega$	-	N12



SCHMATIC DIAGRAM

### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	V <sub>CC</sub>	50	V
Input Voltage, (2) to (1)	V <sub>IN</sub>	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5 V <sub>max</sub> -5 V <sub>max</sub>	V
Output Current	I <sub>O</sub>	30 30 70 100 50 100 100	mA
Output Current	I <sub>C</sub> (Max)	100	mA
Power Dissipation (Total)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R <sub>θJA</sub>	416.7	°C/W
Operating and Storage and Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

- Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.  
2. 200mW per element must not be exceeded.

**Electrical Characteristics** @  $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic (DDC143TK & DDC114TK only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	50	—	—	V	$I_C = 50\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	50	—	—	V	$I_C = 1\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	5	—	—	V	$I_E = 50\mu\text{A}$
Collector Cutoff Current	$I_{CBO}$	—	—	0.5	$\mu\text{A}$	$V_{CB} = 50\text{V}$
Emitter Cutoff Current	$I_{EBO}$	—	—	0.5	$\mu\text{A}$	$V_{EB} = 4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.3	V	$I_C/I_B = 2.5\text{mA} / 0.25\text{mA}$ DDC143TK $I_C/I_B = 1\text{mA} / 0.1\text{mA}$ DDC114TK
DC Current Transfer Ratio	$h_{FE}$	100	250	600	—	$I_C = 1\text{mA}, V_{CE} = 5\text{V}$
Input Resistor ( $R_1$ ) Tolerance	$\Delta R_1$	-30	—	+30	%	—
Gain-Bandwidth Product*	$f_T$	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	$V_{I(off)}$	0.5	1.1	—	V	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$
	0.5 0.3 0.5 0.5		1.1 — — 1.1	—	—		
Input Voltage	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	$V_{I(on)}$	—	1.9	3.0	V	$V_O = 0.3, I_O = 5\text{mA}$ $V_O = 0.3, I_O = 2\text{mA}$ $V_O = 0.3, I_O = 1\text{mA}$ $V_O = 0.3, I_O = 5\text{mA}$ $V_O = 0.3, I_O = 10\text{mA}$
	—		1.9 1.9 — 1.1 1.9	3.0 3.0 1.4 1.1 3.0	—		
Output Voltage	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	$V_{O(on)}$	—	0.1	0.3	V	$I_O/I_I = 10\text{mA} / 0.5\text{mA}$ $I_O/I_I = 10\text{mA} / 0.5\text{mA}$ $I_O/I_I = 5\text{mA} / 0.25\text{mA}$ $I_O/I_I = 5\text{mA} / 0.25\text{mA}$ $I_O/I_I = 10\text{mA} / 0.5\text{mA}$
Input Current	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	$I_I$	—	—	0.36 0.18 0.88 3.6 0.88	mA	$V_I = 5\text{V}$
Output Current		$I_{O(off)}$	—	—	0.5	$\mu\text{A}$	$V_{CC} = 50\text{V}, V_I = 0\text{V}$
DC Current Gain	DDC124EK DDC144EK DDC114YK DDC123JK DDC114EK	$G_I$	56 68 68 80 30	—	—	—	$V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 10\text{mA}$ $V_O = 5\text{V}, I_O = 10\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$
Input Resistor ( $R_1$ ) Tolerance		$\Delta R_1$	-30	—	+30	%	—
Resistance Ratio Tolerance		$R_2/R_1$	-20	—	+20	%	—
Gain-Bandwidth Product*		$f_T$	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$

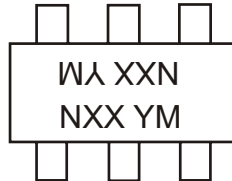
\* Transistor - For Reference Only

## Ordering Information (Note 3)

Device	Packaging	Shipping
DDC124EK-7	SOT-26	3000/Tape & Reel
DDC144EK-7	SOT-26	3000/Tape & Reel
DDC114YK-7	SOT-26	3000/Tape & Reel
DDC123JK-7	SOT-26	3000/Tape & Reel
DDC114EK-7	SOT-26	3000/Tape & Reel
DDC143TK-7	SOT-26	3000/Tape & Reel
DDC114TK-7	SOT-26	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



NXX = Product Type Marking Code  
 See Sheet 1 Diagrams  
 YM = Date Code Marking  
 Y = Year ex: N = 2002  
 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDC123JK  
ONE SECTION

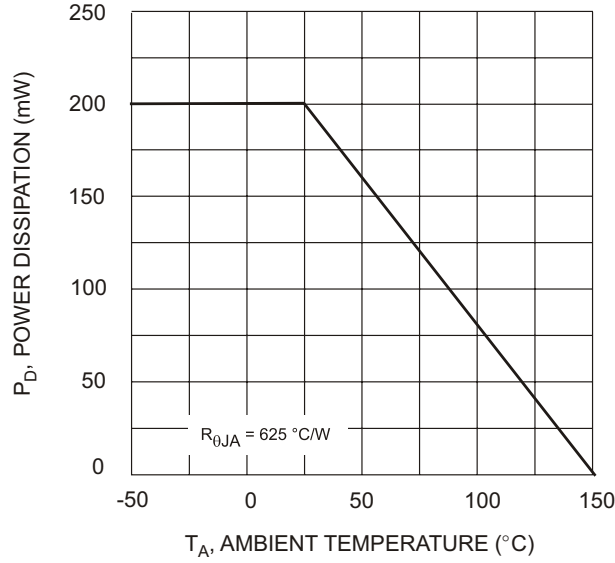


Fig. 1 Derating Curve

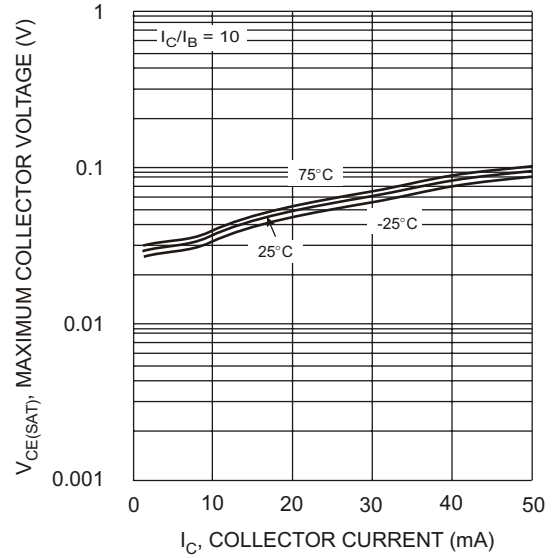


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

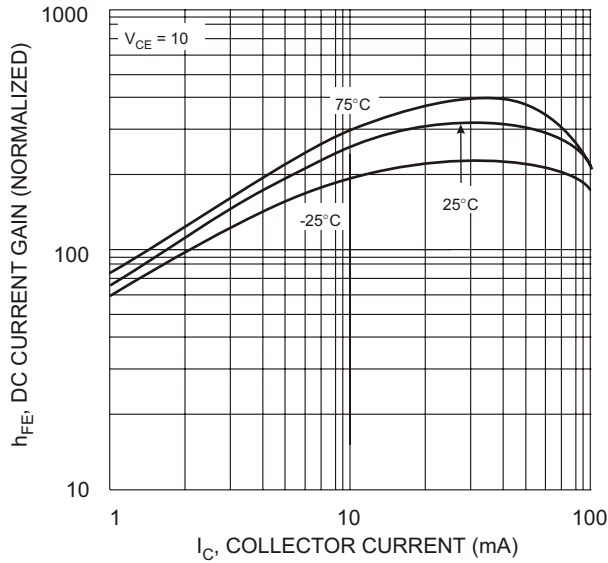


Fig. 3 DC Current Gain

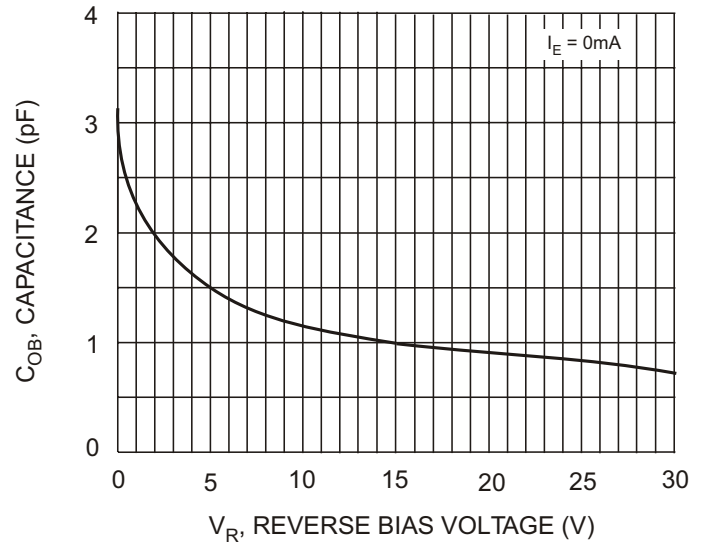


Fig. 4 Output Capacitance

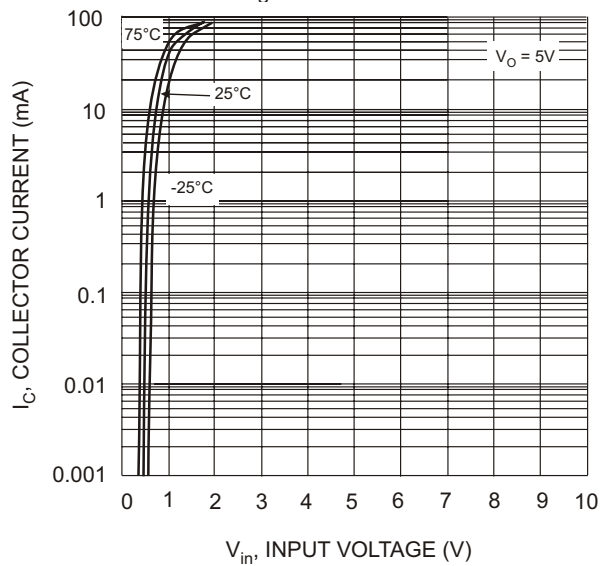


Fig. 5 Collector Current Vs. Input Voltage

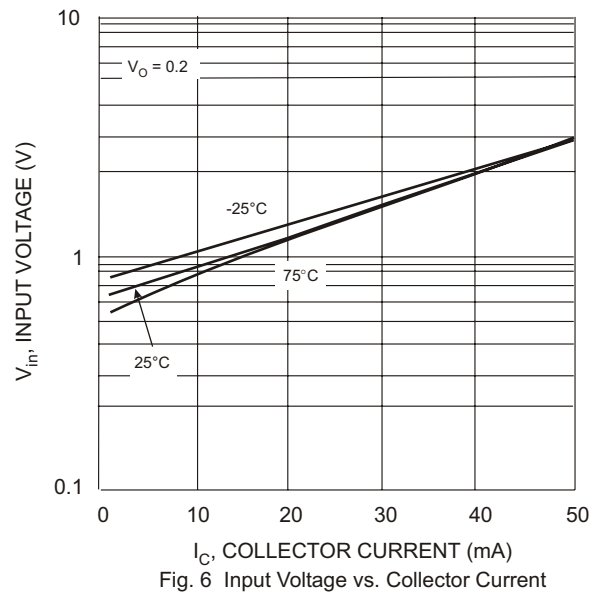


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DDC114TK

ONE SECTION

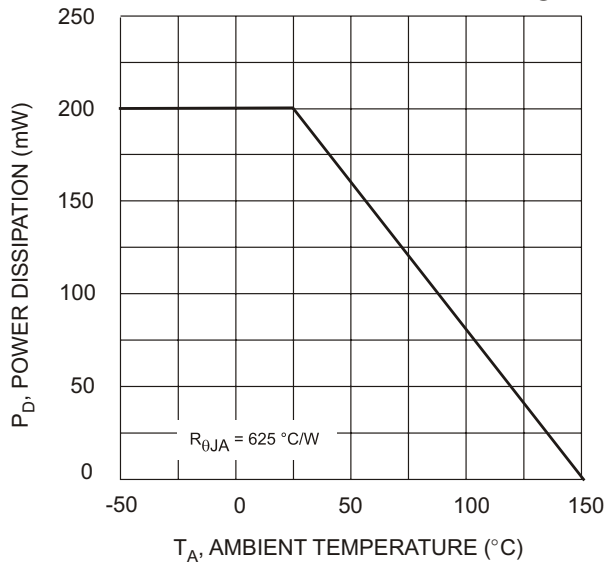


Fig. 1 Derating Curve

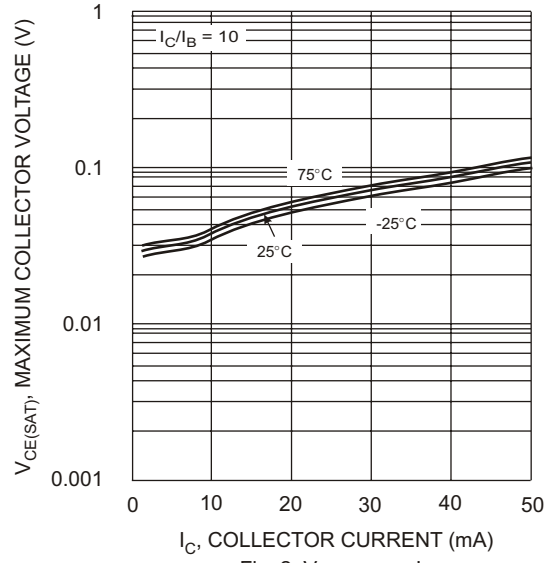


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

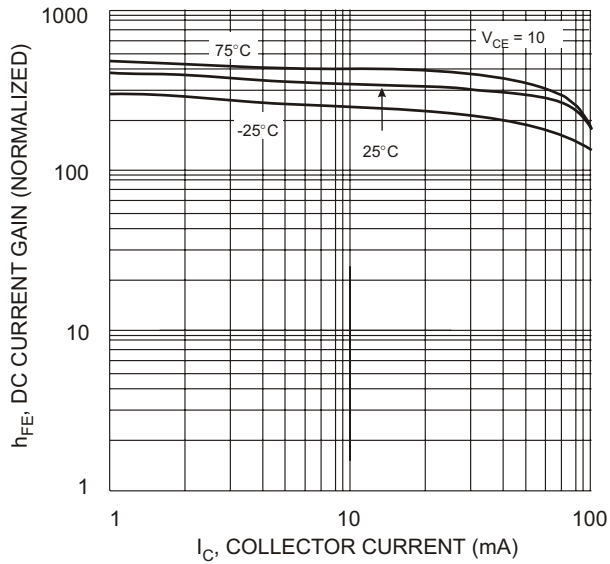


Fig. 3 DC Current Gain

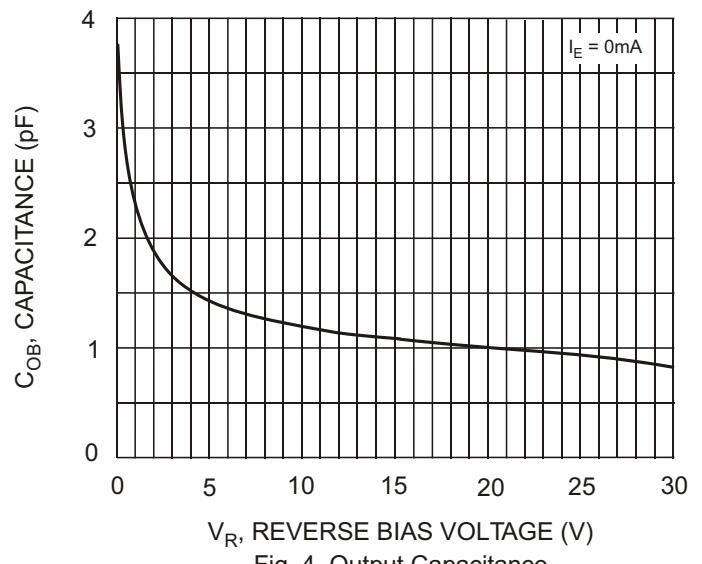


Fig. 4 Output Capacitance

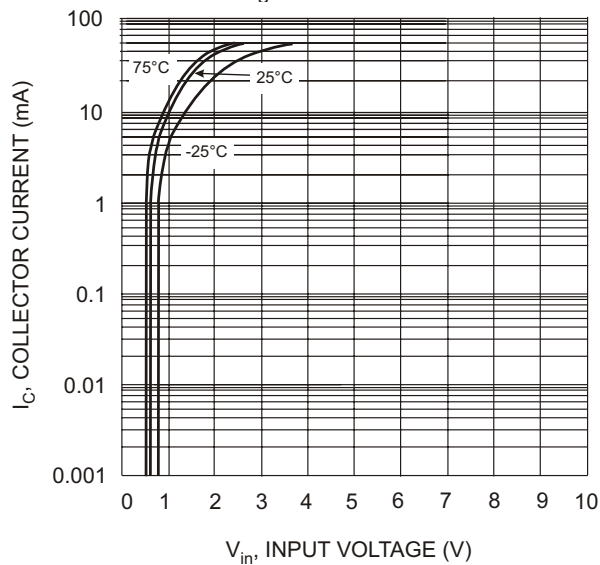


Fig. 5 Collector Current Vs. Input Voltage

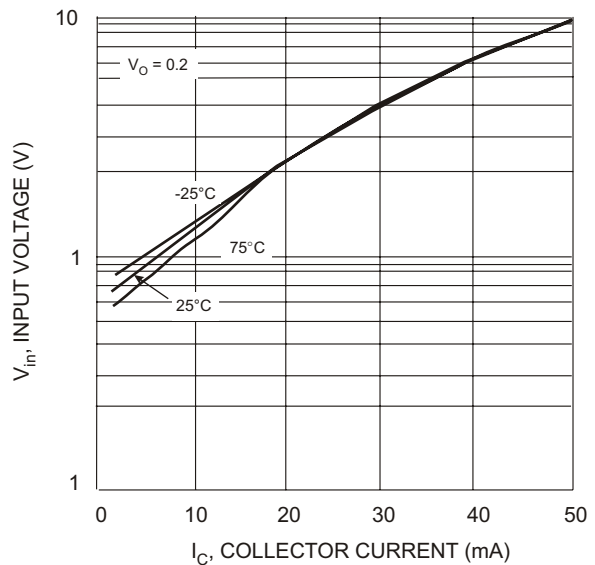


Fig. 6 Input Voltage vs. Collector Current